SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

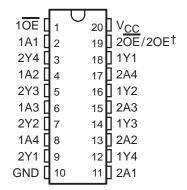
- Open-Collector Outputs Drive Bus Lines or Buffer Memory Address Registers
- Eliminate the Need for 3-State Overlap Protection
- pnp Inputs Reduce dc Loading
- Open-Collector Versions of 'AS240A and 'AS241
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

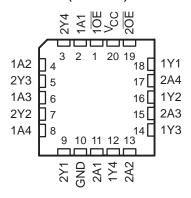
These octal buffers and line drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters by eliminating the need for 3-state overlap protection. The designer has a choice of selected combinations of inverting and noninverting outputs, symmetrical active-low output-enable (\overline{OE}) inputs, and complementary OE and \overline{OE} inputs. These devices feature high fan-out and improved fan-in.

The SN54AS756 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AS756 and SN74AS757 are characterized for operation from 0°C to 70°C.

SN54AS756...J PACKAGE SN74AS756, SN74AS757...DW OR N PACKAGE (TOP VIEW)

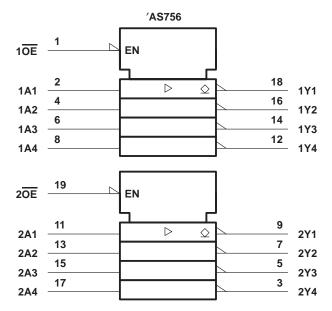


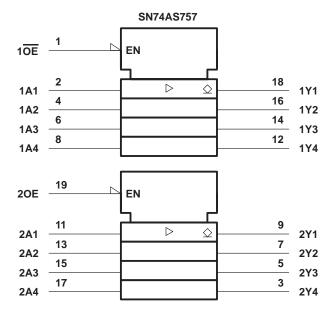
SN54AS756 . . . FK PACKAGE (TOP VIEW)



†20E for 'AS756 or 20E for SN74AS757

logic symbols‡

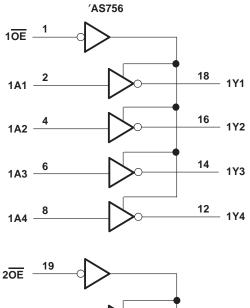


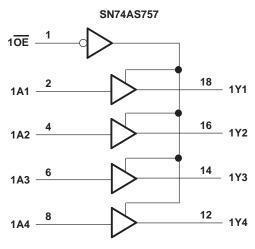


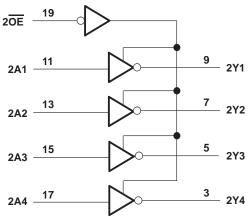
[‡] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

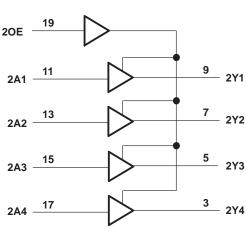
TEXAS INSTRUMENTS SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

logic diagrams (positive logic)









absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}		7 V
Input voltage, V _I		7 V
Off-state output voltage		7 V
Operating free-air temperature range, TA:		
	SN74AS756, SN74AS757	0°C to 70°C
Storage temperature range		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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recommended operating conditions

		SN54AS756			SN SN	UNIT		
		MIN	NOM	MAX	MIN	MIN NOM MAX		
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
Vон	High-level output voltage			5.5			5.5	V
loL	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST	CONDITIONS	SI	N54AS75	56	SN74AS756 SN74AS757			UNIT
						MAX	MIN	TYP [†]	MAX	
VIK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
loh		V _{CC} = 4.5 V,	V _{OH} = 5.5 V			0.1			0.1	mA
.,		451/	$I_{OL} = 48 \text{ mA}$			0.55				V
VOL		V _{CC} = 4.5 V	$I_{OL} = 64 \text{ mA}$						0.55	V
II		V _C C = 5.5 V,	V _I = 7 V			0.1			0.1	mA
lіН		V _C C = 5.5 V,	V _I = 2.7 V			20			20	μΑ
IIL	A inputs of SN74AS757 only	V _{CC} = 5.5 V,	V _I = 0.4 V			-1			-1	mA
'-	All other inputs	7 "	, , ,			-0.5			-0.5	
	44.0750		Outputs high		9	15		9	15	
Icc	'AS756	V _{CC} = 5.5 V	Outputs low		51	80		51	80	A
	SN74AS757	V 55V	Outputs high		21	33		21	33	mA
		V _{CC} = 5.5 V	Outputs low		61	95		61	95	1

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

SN54AS756, SN74AS756, SN74AS757 OCTAL BUFFERS AND LINE DRIVERS WITH OPEN-COLLECTOR OUTPUTS

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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L R _L	= 50 pF = 500 £			UNIT
	, ,	(22 2)	SN54A	NS756	SN74A		
			MIN	MAX	MIN	MAX	
t _{PLH}	Δ.	V	3	20	3	19	
t _{PHL}	A	Y	1	7	1	6	ns
t _{PLH}	ŌĒ	V	3	22	3	19.5	ns
^t PHL	OE .	1	1	8.5	1	7.5	110

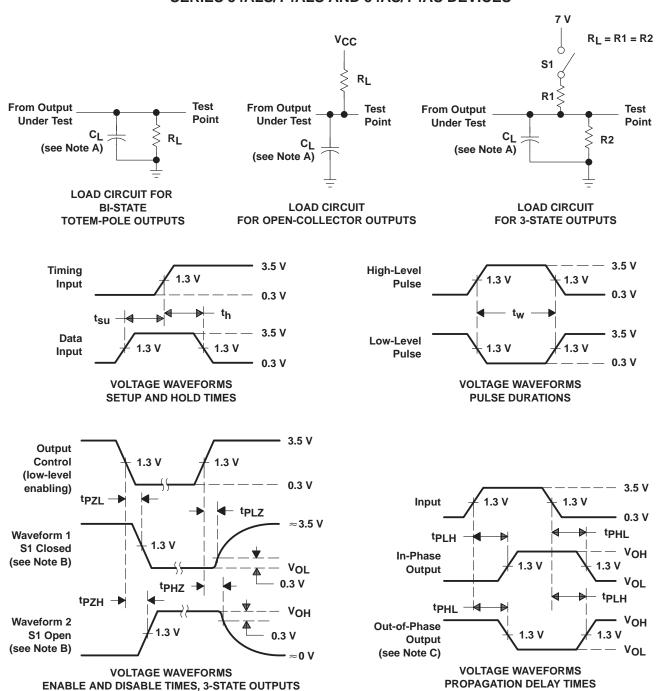
[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	I = I = I = I = I = I = I = I = I = I =						
^t PLH		٧	3	18.5				
t _{PHL}	A	Y	1	6	ns			
^t PLH	1 <u>0E</u>	47	3	20				
t _{PHL}	10E	1Y	1	7	ns			
t _{PLH}	20E	2Y	3	21	ns			
^t PHL	20E	Z Ť	1	7.5	115			

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- All input pulses have the following characteristics: PRR \leq 1 MHz, $t_r = t_f = 2$ ns, duty cycle = 50%.
- The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms







6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-90563012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 90563012A SNJ54AS 756FK	Samples
5962-9056301RA	ACTIVE	CDIP	J	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9056301RA SNJ54AS756J	Samples
5962-9056301SA	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9056301SA SNJ54AS756W	Samples
SN54AS756J	ACTIVE	CDIP	J	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	SN54AS756J	Samples
SN74AS756DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS756	Samples
SN74AS756N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS756N	Samples
SN74AS757DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS757	Samples
SN74AS757DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS757	Samples
SN74AS757N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS757N	Samples
SNJ54AS756FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 90563012A SNJ54AS 756FK	Samples
SNJ54AS756J	ACTIVE	CDIP	J	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9056301RA SNJ54AS756J	Samples
SNJ54AS756W	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9056301SA SNJ54AS756W	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

6-Feb-2020

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AS756, SN74AS756:

Catalog: SN74AS756

www.ti.com

Military: SN54AS756

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

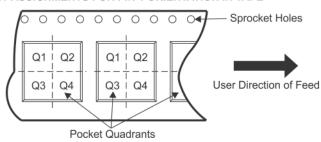
TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
1	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AS757DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

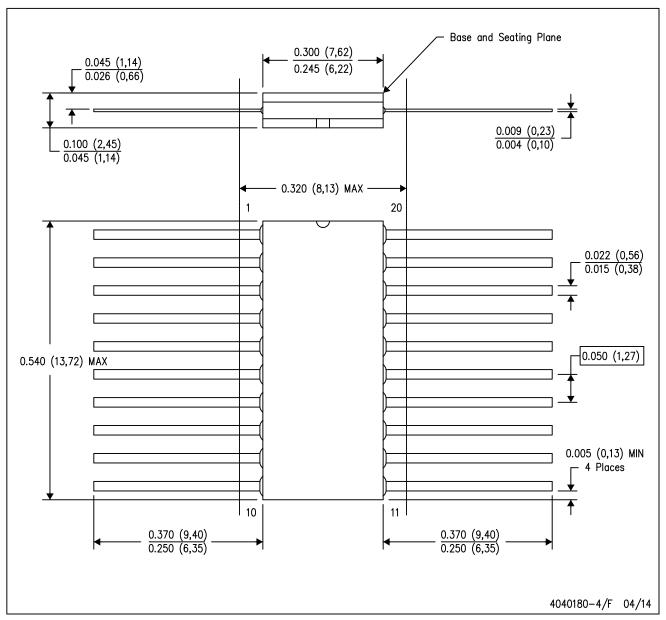


*All dimensions are nominal

I	Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	SN74AS757DWR	SOIC	DW	20	2000	367.0	367.0	45.0

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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